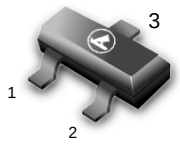
General Purpose Transistors

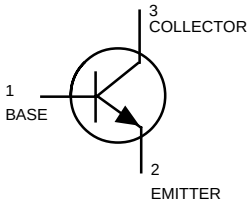
NPN Silicon

- We declare that the material of product compliance with RoHS requirements.
- S- Prefix for Automotive and Other Applications Requiring Unique Site and Control Change Requirements; AEC-Q101 Qualified and PPAP Capable.

LMBT2222LT1G
LMBT2222ALT1G
S-LMBT2222LT1G
S-LMBT2222ALT1G



SOT– 23



MAXIMUM RATINGS

Rating	Symbol	2222	2222A	Unit
Collector–Emitter Voltage	V_{CEO}	30	40	Vdc
Collector–Base Voltage	V_{CBO}	60	75	Vdc
Emitter–Base Voltage	V_{EBO}	5.0	6.0	Vdc
Collector Current — Continuous	I_C	600	600	mAdc

THERMAL CHARACTERISTICS

Characteristic	Symbol	Max	Unit
Total Device Dissipation FR– 5 Board, (1) T_A = 25°C	P_D	225	mW
Derate above 25°C		1.8	mW/°C
Thermal Resistance, Junction to Ambient	$R_{\theta JA}$	556	°C/W
Total Device Dissipation Alumina Substrate, (2) T_A = 25°C	P_D	300	mW
Derate above 25°C		2.4	mW/°C
Thermal Resistance, Junction to Ambient	$R_{\theta JA}$	417	°C/W
Junction and Storage Temperature	T_J , T_{stg}	–55 to +150	°C

ORDERING INFORMATION

Device	Marking	Shipping
LMBT2222LT1G S-LMBT2222LT1G	M1B M1B	3000/Tape & Reel
LMBT2222LT3G S-LMBT2222LT3G	M1B M1B	10000/Tape & Reel
LMBT2222ALT1G S-LMBT2222ALT1G	1P	3000/Tape & Reel
LMBT2222ALT3G S-LMBT2222ALT3G	1P	10000/Tape & Reel

DEVICE MARKING

LMBT2222LT1G = M1B; LMBT2222ALT1G = 1P

ELECTRICAL CHARACTERISTICS (T_A = 25°C unless otherwise noted.)

Characteristic		Symbol	Min	Max	Unit
OFF CHARACTERISTICS					
Collector–Emitter Breakdown Voltage	LMBT2222	$V_{(BR)CEO}$	30	—	Vdc
(I_C = 10 mAdc, I_B = 0)	LMBT2222A		40	—	
Collector–Base Breakdown Voltage	LMBT2222	$V_{(BR)CBO}$	60	—	Vdc
(I_C = 10 µAdc, I_E = 0)	LMBT2222A		75		
Emitter–Base Breakdown Voltage	LMBT2222	$V_{(BR)EBO}$	5.0	—	Vdc
(I_E = 10 µAdc, I_C = 0)	LMBT2222A		6.0	—	
Collector Cutoff Current	LMBT2222A	I_{CEX}	—	10	nAdc
(V_{CE} = 60 Vdc, $I_{EB(off)}$ = 3.0Vdc)					
Collector Cutoff Current		I_{CBO}			µAdc
(V_{CB} = 50 Vdc, I_E = 0)	LMBT2222		—	0.01	
(V_{CB} = 60 Vdc, I_E = 0)	LMBT2222A		—	0.01	
(V_{CB} = 50 Vdc, I_E = 0, T_A = 125°C)	LMBT2222		—	10	
(V_{CB} = 60 Vdc, I_E = 0, T_A = 125°C)	LMBT2222A		—	10	
Emitter Cutoff Current					
(V_{EB} = 3.0 Vdc, I_C = 0)	LMBT2222A	I_{EBO}	—	100	nAdc
Base Cutoff Current					
(V_{CE} = 60 Vdc, $V_{EB(off)}$ = 3.0 Vdc)	LMBT2222A	I_{BL}	—	20	nAdc

1. FR–5 = 1.0 x 0.75 x 0.062 in.
2. Alumina = 0.4 x 0.3 x 0.024 in. 99.5% alumina.

LMBT2222LT1G LMBT2222ALT1G
S-LMBT2222LT1G S-LMBT2222ALT1G

ELECTRICAL CHARACTERISTICS (T A = 25°C unless otherwise noted) (Continued)

Characteristic		Symbol	Min	Max	Unit
ON CHARACTERISTICS					
DC Current Gain		h_{FE}			—
(I_C = 0.1 mAdc, V_{CE} = 10 Vdc)			35	—	
(I_C = 1.0 mAdc, V_{CE} = 10 Vdc)			50	—	
(I_C = 10 mAdc, V_{CE} = 10 Vdc)			75	—	
(I_C = 10 mAdc, V_{CE} = 10 Vdc,T_A = –55°C)	LMBT2222A only		35	—	
(I_C = 150 mAdc, V_{CE} = 10 Vdc) (3)			100	300	
(I_C = 150 mAdc, V_{CE} = 1.0 Vdc) (3)			50	—	
(I_C = 500 mAdc, V_{CE} = 10 Vdc)(3)	LMBT2222		30	—	
	LMBT2222A		40	—	
Collector–Emitter Saturation Voltage(3)		$V_{CE(sat)}$			Vdc
(I_C = 150 mAdc, I_B = 15 mAdc)	LMBT2222		—	0.4	
	LMBT2222A		—	0.3	
(I_C = 500mAdc, I_B = 50 mAdc)	LMBT2222		—	1.6	
	LMBT2222A		—	1.0	
Base–Emitter Saturation Voltage		$V_{BE(sat)}$			Vdc
(I_C = 150 mAdc, I_B = 15 mAdc)	LMBT2222		—	1.3	
	LMBT2222A		0.6	1.2	
(I_C = 500 mAdc, I_B = 50 mAdc)	LMBT2222		—	2.6	
	LMBT2222A		—	2.0	
SMALL–SIGNAL CHARACTERISTICS					
Current–Gain — Bandwidth Product(4)	LMBT2222	f_T	250	—	MHz
(I_C = 20mAdc, V_{CE}= 20Vdc, f = 100MHz)	LMBT2222A		300	—	
Output Capacitance(V_{CB} = 10 Vdc, I_E = 0, f = 1.0 MHz)		C_{obo}	—	8.0	pF
Input Capacitance	LMBT2222	C_{ibo}	—	30	pF
(V_{EB} = 0.5 Vdc, I_C = 0, f = 1.0 MHz)	LMBT2222A		—	25	
Input Impedance(V_{CE}= 10 Vdc, I_C = 1.0 mAdc, f = 1.0 kHz)	LMBT2222A	h_{ie}	2.0	8.0	kΩ
(V_{CE}= 10 Vdc, I_C = 10 mAdc, f = 1.0 kHz)	LMBT2222A		0.25	1.25	
Voltage Feedback Ratio(V_{CE}=10 Vdc, I_C= 1.0mAdc, f =1.0kHz)	LMBT2222A	h_{re}	–-	8.0	X 10^{-4}
(V_{CE}= 10 Vdc, I_C = 10 mAdc, f = 1.0 kHz)	LMBT2222A		—	4.0	
Small–Signal Current Gain(V_{CE}=10Vdc,I_C=1.0mAdc, f=1.0kHz)	LMBT2222A	h_{fe}	50	300	—
(V_{CE}= 10 Vdc, I_C = 10 mAdc, f = 1.0 kHz)	LMBT2222A		75	375	
Output Admittance(V_{CE}=10 Vdc, I_C = 1.0 mAdc,f =1.0 kHz)	LMBT2222A	h_{oe}	5.0	35	µmhos
(V_{CE}= 10 Vdc, I_C = 10 mAdc, f = 1.0 kHz)	LMBT2222A		25	200	
Curren Base Time Comstant					
(V_{CB}= 20 Vdc, I_E = 20 mAdc, f = 31.8 MHz)	LMBT2222A	rb, C_C	—	150	ps
Noise Figure(V_{CE}=10Vdc, I_C=100µAdc, R_S=1.0kΩ, f =1.0kHz)	LMBT2222A	NF	—	4.0	dB

SWITCHING CHARACTERISTICS

Delay Time	(V_{CC} = 30 Vdc, $V_{EB(off)}$ = – 0.5 Vdc	t_d	—	10	
Rise Time	I_C = 150 mAdc, I_{B1} = 15 mAdc)	t_r	—	25	ns
Storage Time	(V_{CC} = 30 Vdc, I_C = 150 mAdc	t_s	—	225	ns
Fall Time	I_{B1} = I_{B2} = 15 mAdc)	t_f	—	60	

3. Pulse Test: Pulse Width ≤300 µs, Duty Cycle ≤2.0%.

4.f_T is defined as the frequency at which $|h_{fe}|$ extrapolates to unity.

LMBT2222LT1G LMBT2222ALT1G
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SWITCHING TIME EQUIVALENT TEST CIRCUITS

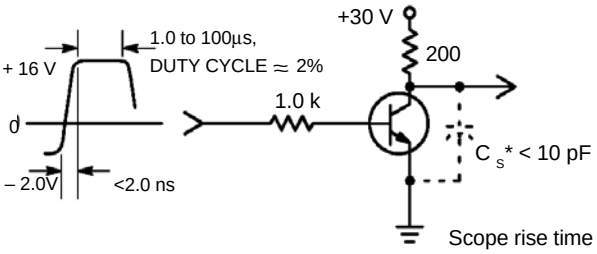

Figure 1. Turn–On Time

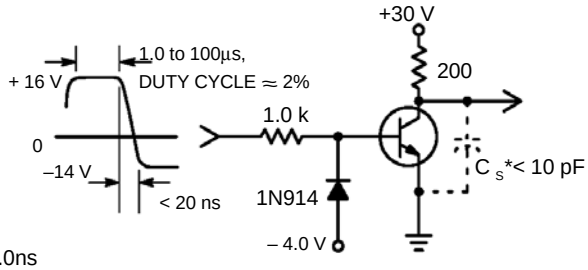

Figure 2. Turn–Off Time

Scope rise time < 4.0ns
*Total shunt capacitance of test jig, connectors, and oscilloscope.

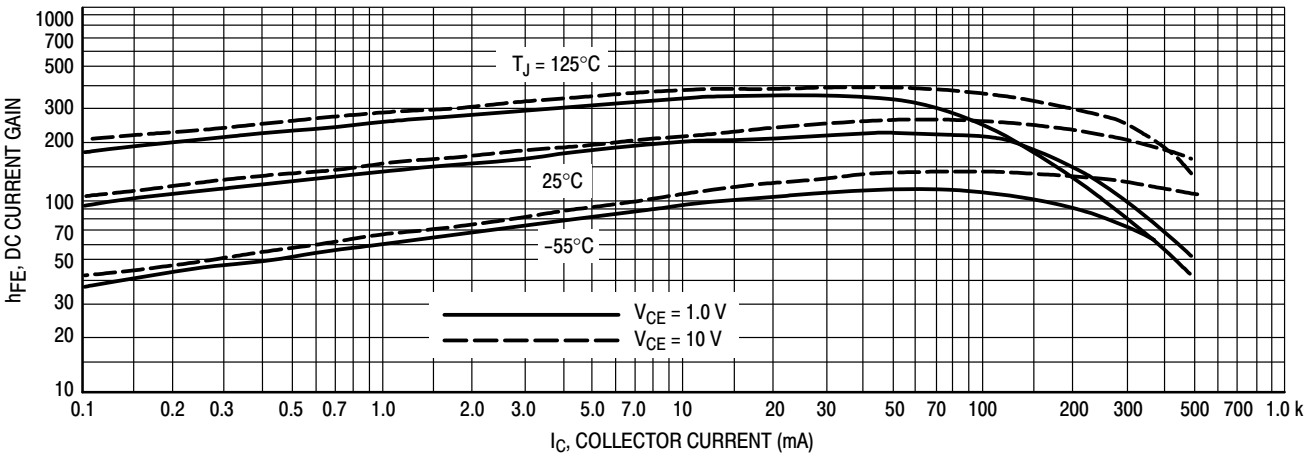

Figure 3. DC Current Gain

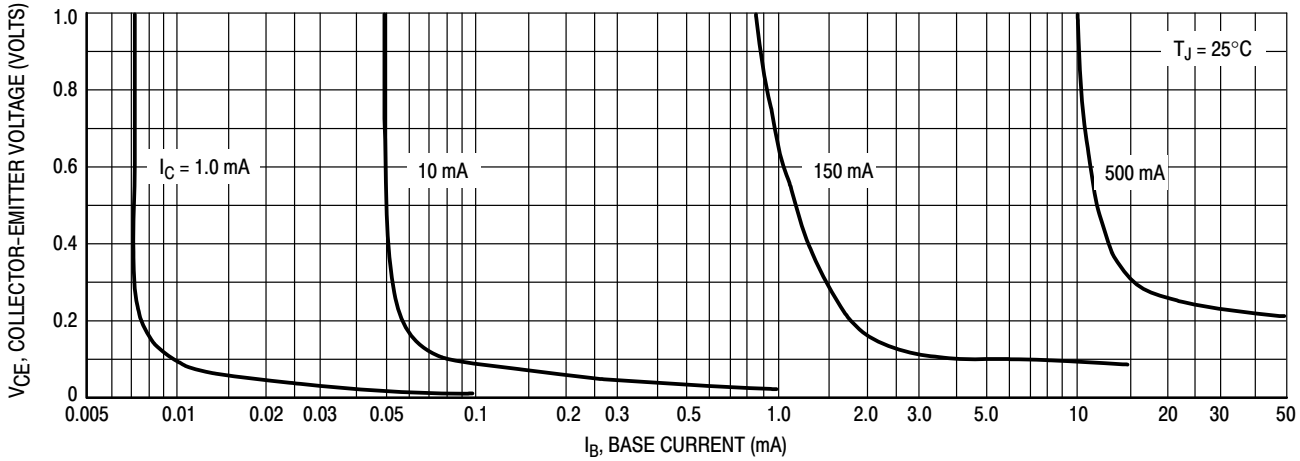

Figure 4. Collector Saturation Region

LMBT2222LT1G LMBT2222ALT1G
S-LMBT2222LT1G S-LMBT2222ALT1G

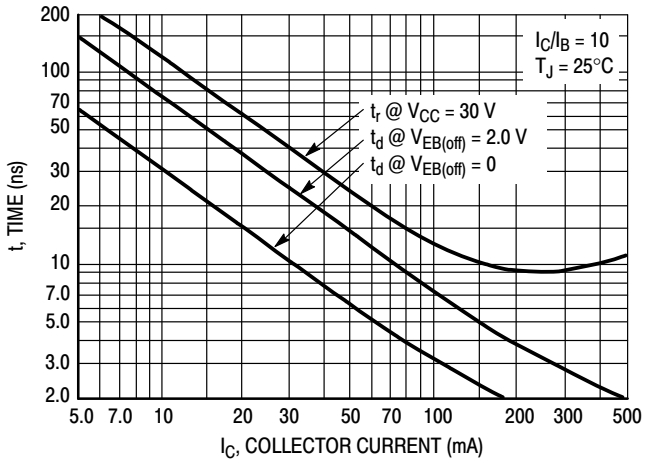

Figure 5. Turn–On Time

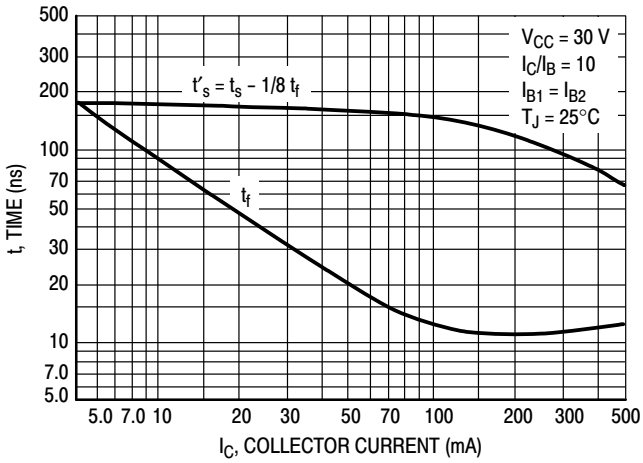

Figure 6. Turn - Off Time

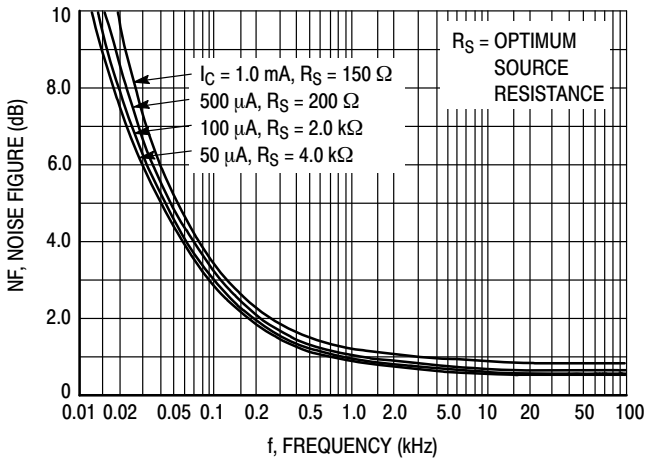

Figure 7. Frequency Effects

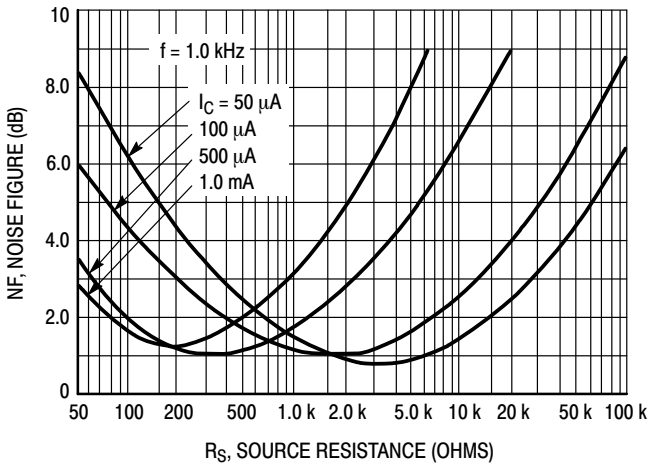

Figure 8. Source Resistance Effects

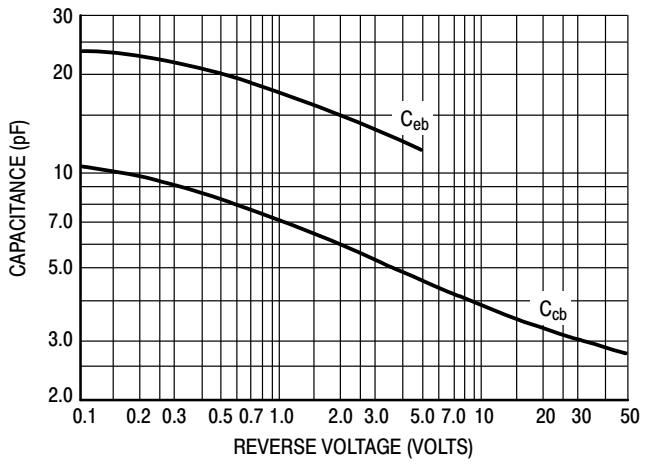

Figure 9. Capacitances

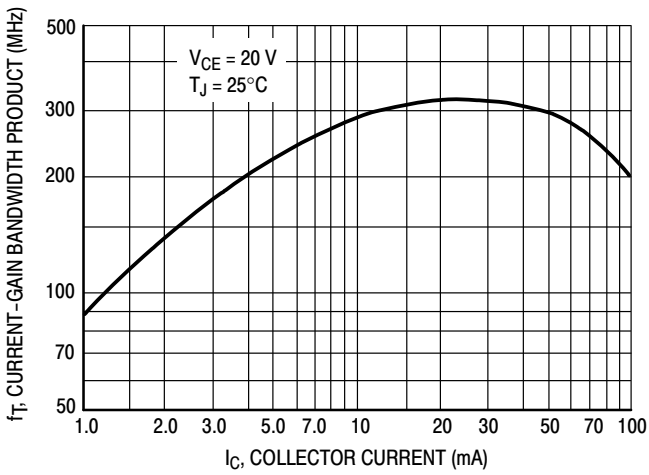

Figure 10. Current–Gain Bandwidth Product

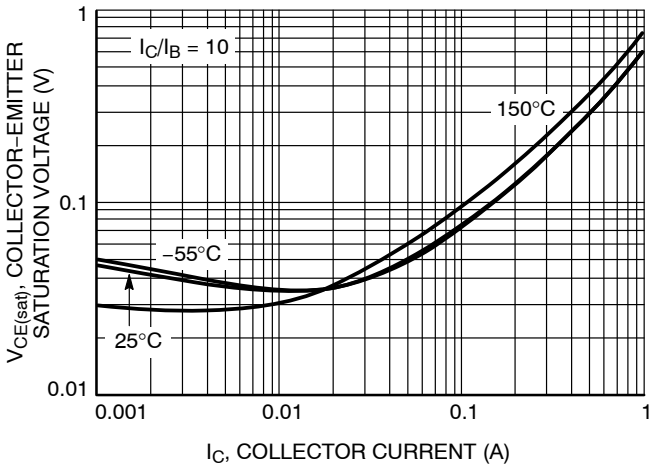

Figure 11. Collector Emitter Saturation Voltage vs. Collector Current

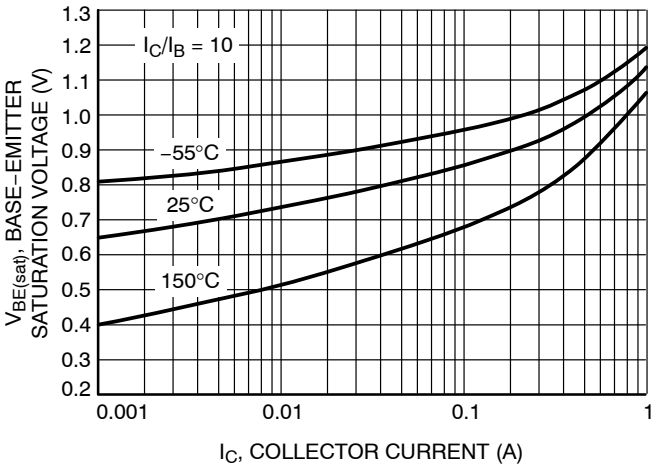

Figure 12. Base Emitter Saturation Voltage vs. Collector Current

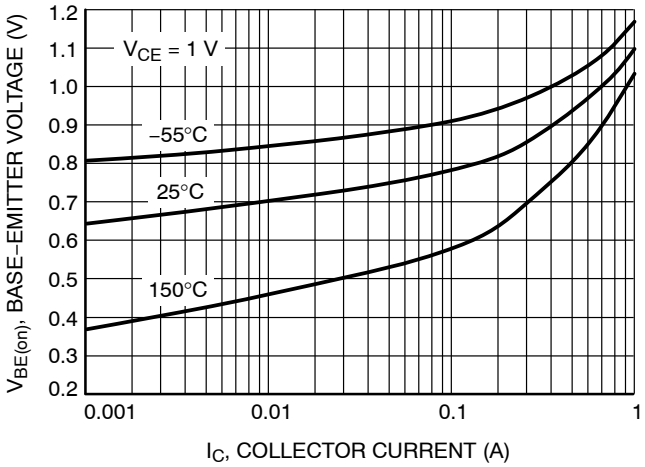

Figure 13. Base Emitter Voltage vs. Collector Current

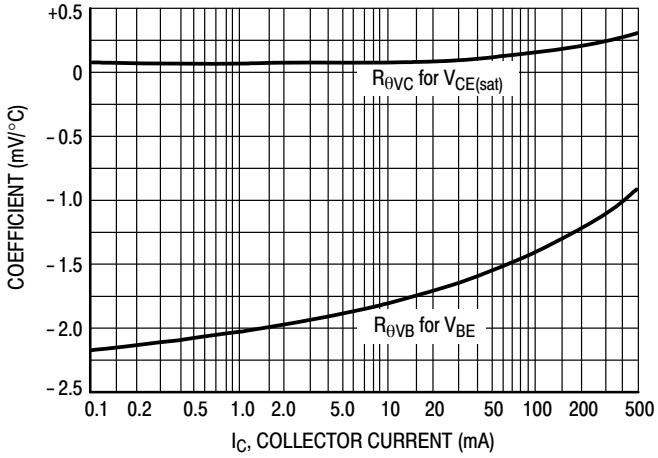

Figure 14. Temperature Coefficients

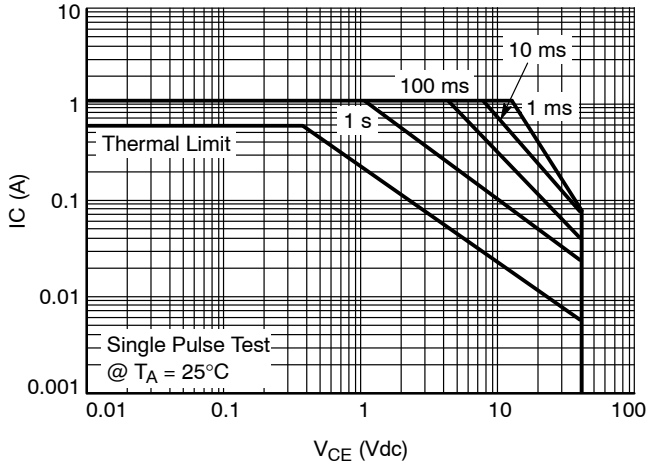

Figure 15. Safe Operating Area

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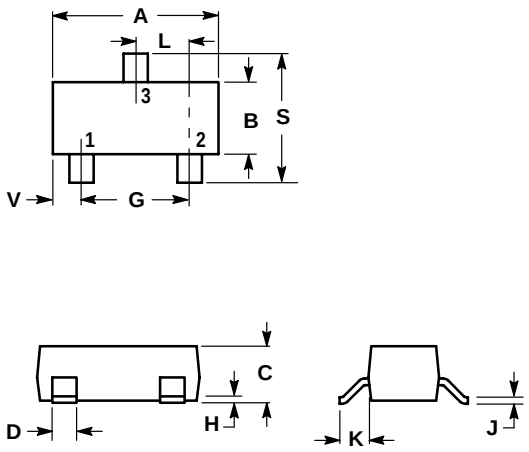

NOTES:

1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M,1982
2. CONTROLLING DIMENSION: INCH.

DIM	INCHES		MILLIMETERS	
	MIN	MAX	MIN	MAX
A	0.1102	0.1197	2.80	3.04
B	0.0472	0.0551	1.20	1.40
C	0.0350	0.0440	0.89	1.11
D	0.0150	0.0200	0.37	0.50
G	0.0701	0.0807	1.78	2.04
H	0.0005	0.0040	0.013	0.100
J	0.0034	0.0070	0.085	0.177
K	0.0140	0.0285	0.35	0.69
L	0.0350	0.0401	0.89	1.02
S	0.0830	0.1039	2.10	2.64
V	0.0177	0.0236	0.45	0.60